

# **Vorlesung 22**

## **Rastertunnelspektroskopie**

## Übersicht über die Kapitel der Vorlesung

0. Motivation
1. Die Oberfläche
2. Dünne Gase
3. Methoden der Oberflächenphysik
4. Schichtwachstum
5. Oberflächenchemie
6. Elektronische Struktur von Oberflächen
- 7. Oberflächenmagnetismus**
- 8. Quantennanowissenschaften auf Oberflächen**

## **Lernziele**

- Rastertunnelspektroskopie
- Oberflächenzustände
- Kondo-Effekt

## 3.7 Rastertunnelmikroskopie - Wiederholung

### Quantenmechanik des Tunnelns

- Transmission sieht ähnlich aus für Trapez-Barriere:

$$\mathcal{T}(E, U, \Phi, z_0 + \Delta z) = \exp\left(-2\sqrt{\frac{2m}{\hbar^2}}\sqrt{\Phi + \frac{eU}{2} - E}\right)(z_0 + \Delta z).$$

- Wichtig:** Höhe der Barriere bestimmt durch Austrittsarbeiten

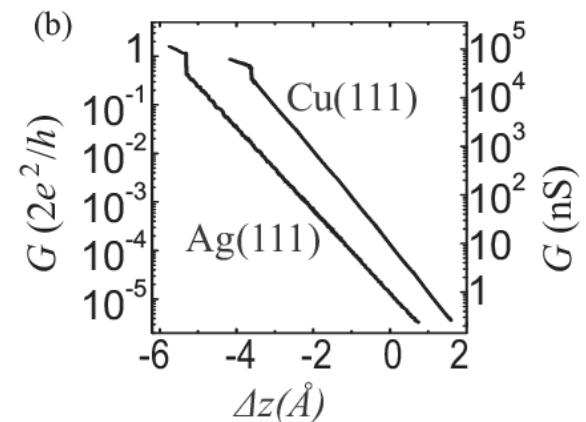
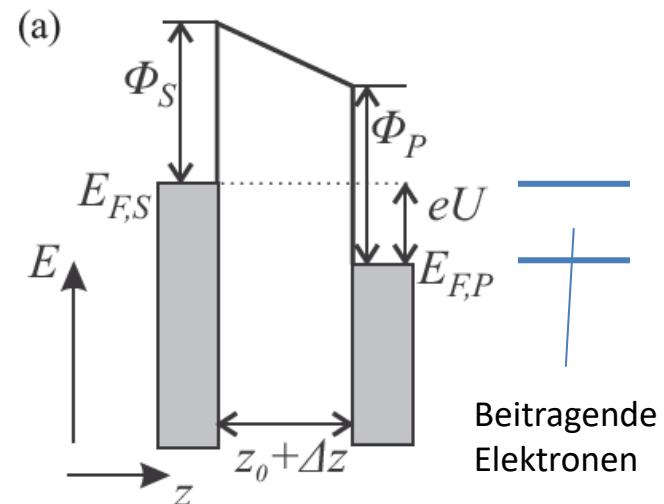
$$\Phi = (\Phi_P + \Phi_S)/2$$

- Für kleine Tunnelspannungen:**

$$I(\Delta z) = I(z_0)e^{-\alpha\Delta z}; \alpha = 2\sqrt{2m\Phi}/\hbar = 10,25 \text{ nm}^{-1}(\Phi/\text{eV})^{-1/2}.$$

Table 1.1: Work functions and decay constants

Element	Al	Au	Cu	Ir	Ni	Pt	Si	W
$\phi$ (eV)	4.1	5.4	4.6	5.6	5.2	5.7	4.8	4.8
$\kappa$ (nm <sup>-1</sup> )	10.3	11.9	10.9	12.1	11.6	12.2	11.2	11.2



Fauster, S. 130

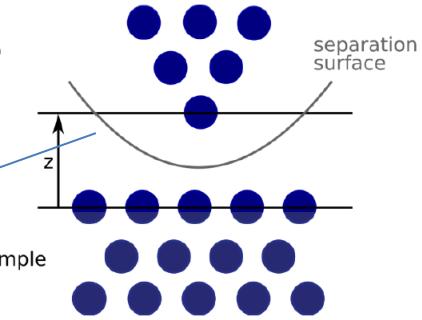
## 3.7 Rastertunnelmikroskopie - Wiederholung

### Bardeen Approach

- Vor der Erfindung des STMs
- Elektronentunneln für ein System von planaren Tunnelübergängen, behandelt in einem zeitabhängigen Störungstheorie-Ansatz
- Transfermatrix-Element

Stromdichte-Operator

$$M_{\mu\nu} = -\frac{\hbar^2}{2m} \int [\psi_\mu^* \nabla \psi_\nu - \psi_\nu \nabla \psi_\mu^*] dS$$



Daraus folgt der Tunnelstrom durch Summation

Transfer-Raten nach  
Fermis goldener Regel

$$I_T(V) = \frac{2\pi e}{\hbar} \sum_{\mu,\nu} [f(E_\mu) - f(E_\nu)] |M_{\mu\nu}|^2 \delta(E_\nu + V - E_\mu) \approx \frac{2\pi}{\hbar} e^2 V \sum_{\mu,\nu} |M_{\mu\nu}|^2 \delta(E_\mu - E_F) \delta(E_\nu - E_F)$$

Low temperatures

Im Limes ergibt dies

$$I_T(V) \propto \int [f_s(\varepsilon - eV) - f_t(\varepsilon)] \rho_S(\varepsilon - eV) \rho_T(\varepsilon) |M(\varepsilon, eV)|^2 d\varepsilon$$

## 3.7 Rastertunnelmikroskopie - Wiederholung

### Beschreibung des Tunnelprozesses nach Tersoff-Hamann

- Spitze wird durch ein sphärisches Potential beschrieben mit s-artigem Charakter
- Unter dieser Näherungen zeigt ein Konstantstrombild die Fläche gleicher Elektronendichte.

Zustandsdichte Spitze

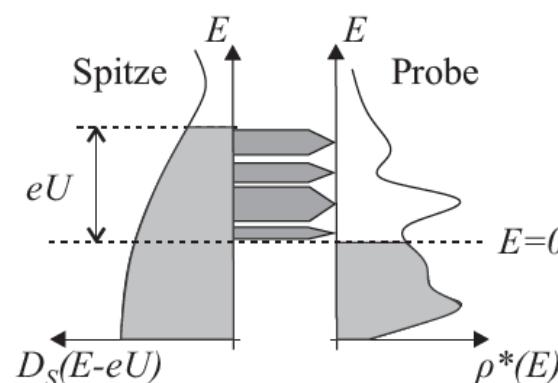
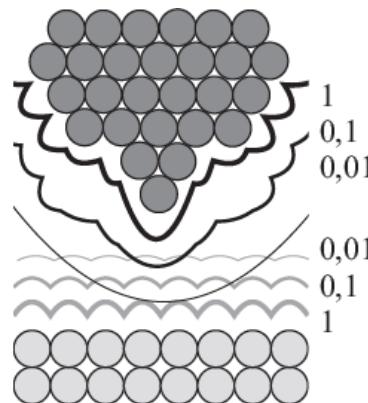
$$I(x,y,z,U) \propto \int_{-\infty}^{\infty} D_S(E - eU) \rho(x,y,z,E) (f(E - eU, T_S) - f(E, T_P)) dE$$

Für tiefe Temperaturen:  $T_P = T_S = 0$

$$I(x,y,z,U) \propto \int_0^{eU} D_S(E - eU) \rho^*(x,y,E) \mathcal{T}(E, U, z) dE.$$

Zustandsdichte Probe

Transmissionsfunktion



Fauster, S. 134

## 6.11 Rastertunnelspektroskopie

### Rastertunnelspektroskopie nach Tersoff-Hamann

- Rastertunnelspektroskopie: lokale elektronische Struktur der Oberfläche

$$I(x,y,z,U) \propto \int_0^{eU} D_S(E - eU) \rho^*(x,y,E) \mathcal{T}(E,U,z) dE.$$



$$\frac{\partial}{\partial U} I(x,y,z_0,U) \propto e \mathcal{T}(eU,U,z_0) D_S(0) \rho^*(x,y,eU)$$

Zustandsdichte der Probe

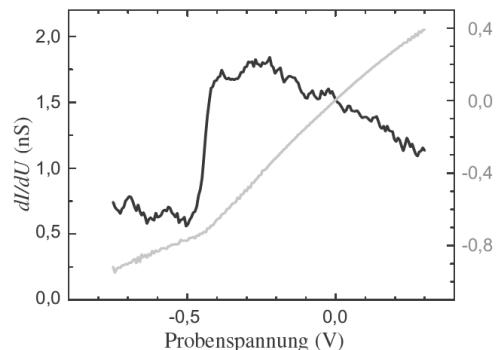
$$+ \int_0^{eU} \rho^*(x,y,E) \mathcal{T}(E,U,z_0) \frac{\partial}{\partial U} D_S(E - eU) dE$$

$$+ \int_0^{eU} \rho^*(x,y,E) D_S(E - eU) \frac{\partial}{\partial U} \mathcal{T}(E,U,z_0) dE.$$

Gute Spitze?

(6.4) Hintergrund

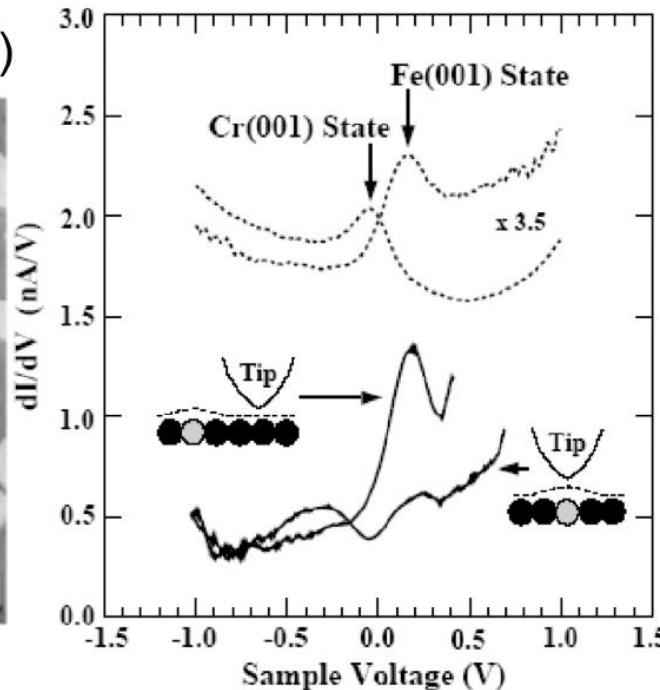
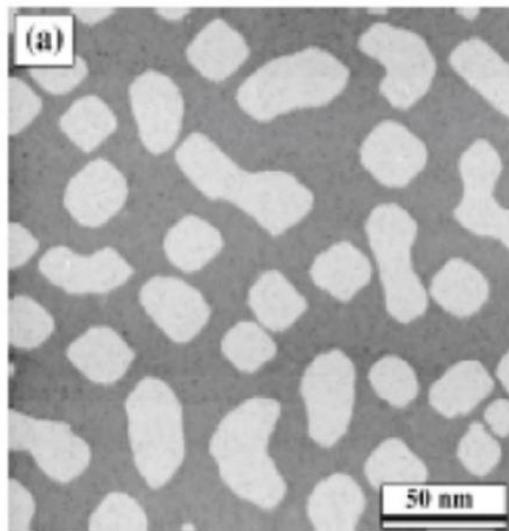
**Abb. 6.7:**  $I(U)$ -Kennlinie (grau, rechte Skala) und STS-Spektrum (schwarz, linke Skala) bei  $T = 6\text{ K}$  auf einer ausgedehnten Terrasse eines Cu(111)-Kristalls aufgenommen. Der starke Anstieg des  $dI/dU$ -Signals bei  $-0,44\text{ V}$  zeigt das Bandminimum des Oberflächenzustands an.



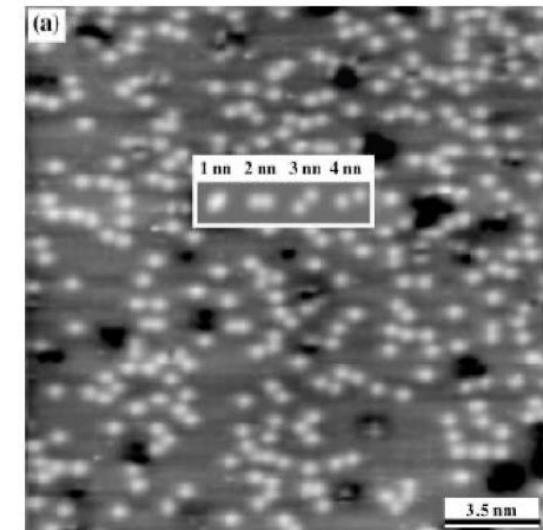
## 6.11 Rastertunnelspektroskopie

- “chemische” Auflösung
- Legierungsbildung an der Cr-Fe(001)-Grenzfläche

Topographie Cr/Fe(001)



$dI/dV$  bei -0.3 V

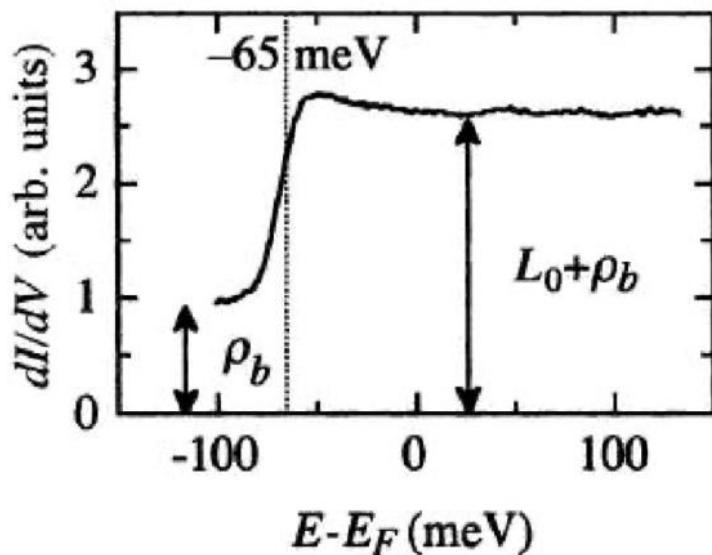


- Cr und Fe haben ihre spezifischen lokalen Zustandsdichten die einem elektronischen „Fingerabdruck“ gleich kommen.
- Lokale Messung von  $dI/dV$  ermöglicht atomare chemische Identifikation.

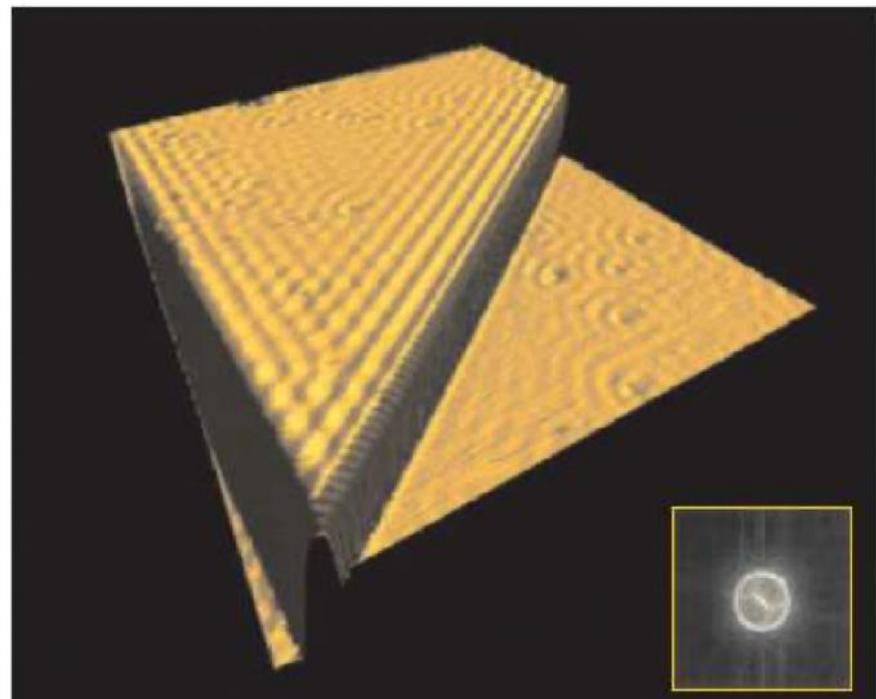
## 6.11 Rastertunnelspektroskopie

Der Oberflächenzustand von Ag(111)

Tunnelspektrum



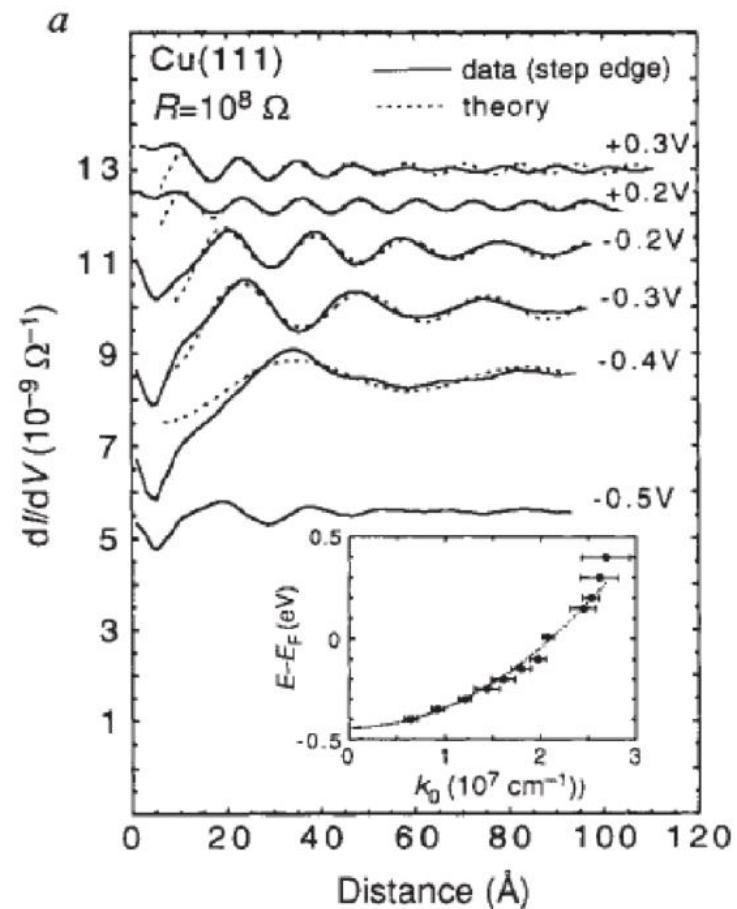
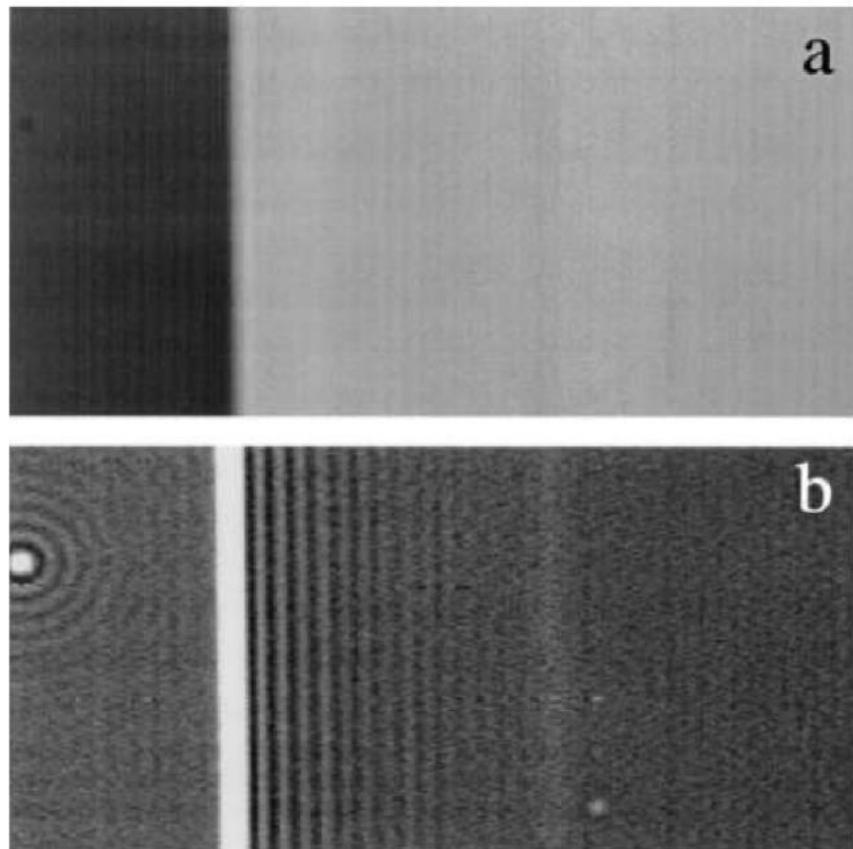
Topographie



- Oberflächenzustand erzeugt Stufe in der differentiellen Leitfähigkeit, da die Zustandsdichte konstant ist.
- Der Oberflächenzustand wird an Stufen und Defekten gestreut.

## 6.11 Rastertunnelspektroskopie

### Der Oberflächenzustand von Cu(111)

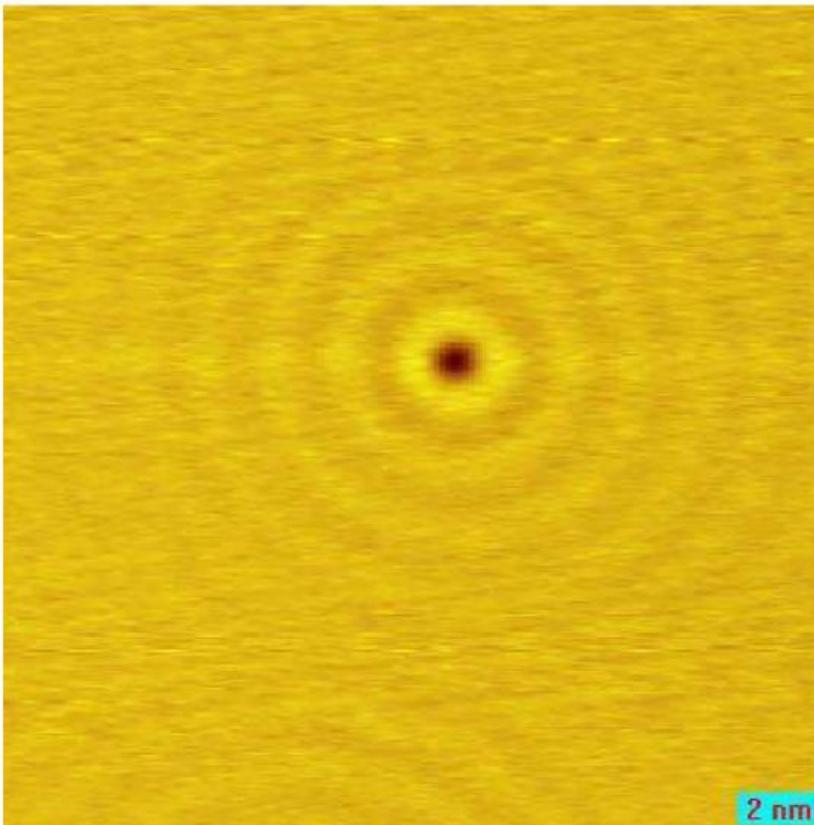


Effektive Masse  $m^*/m_0 = 0.38$ , Bandkante -0.4 eV

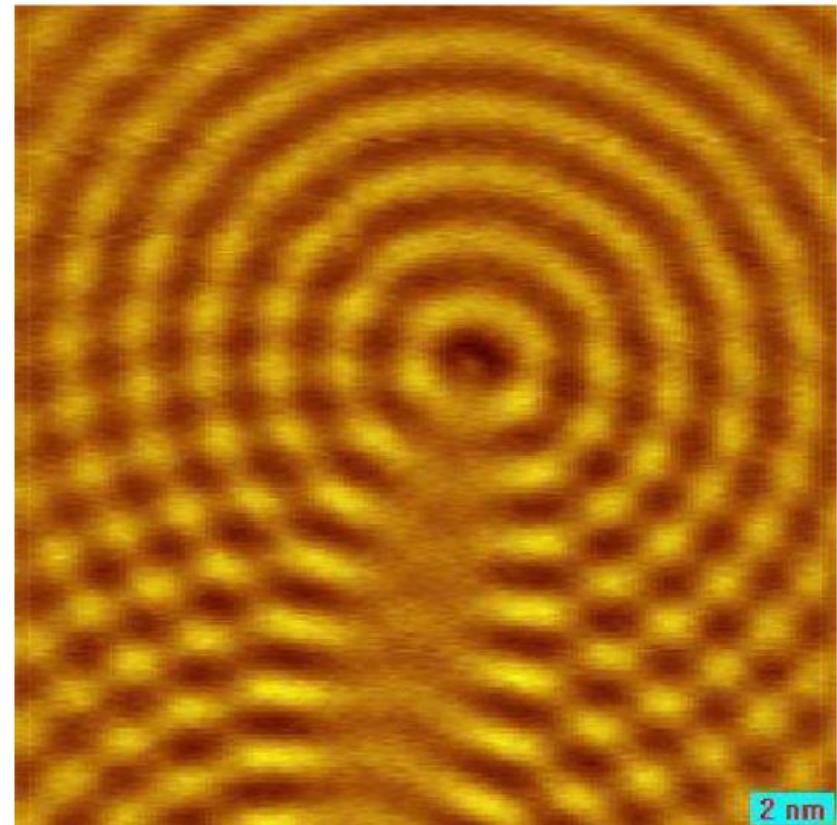
## 6.11 Rastertunnelspektroskopie

Der Oberflächenzustand von Cu(111)

Topographie

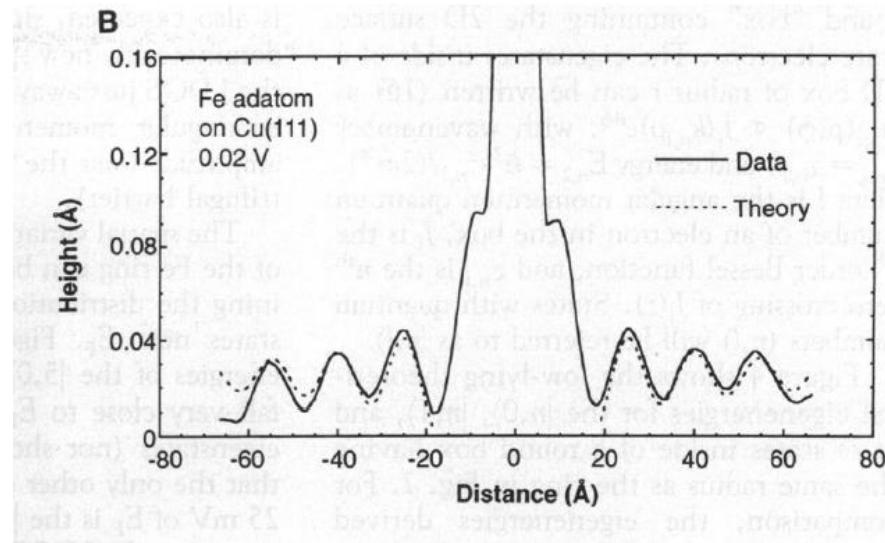
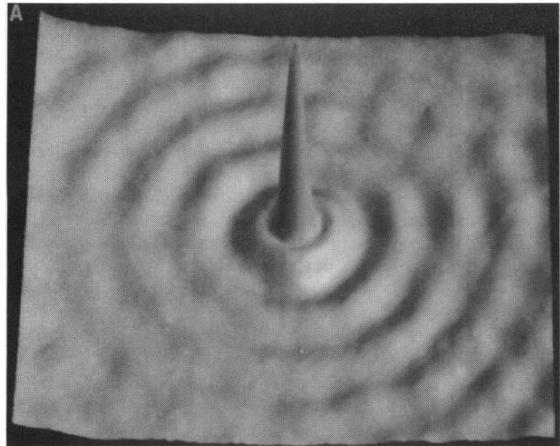


$dI/dV$  bei 50mV



Streuung an einzelnen Defekten (hier CO) führt zu stehenden Wellen in der Topographie und in der lokalen Zustandsdichte.

## Fe atom on Cu(111)



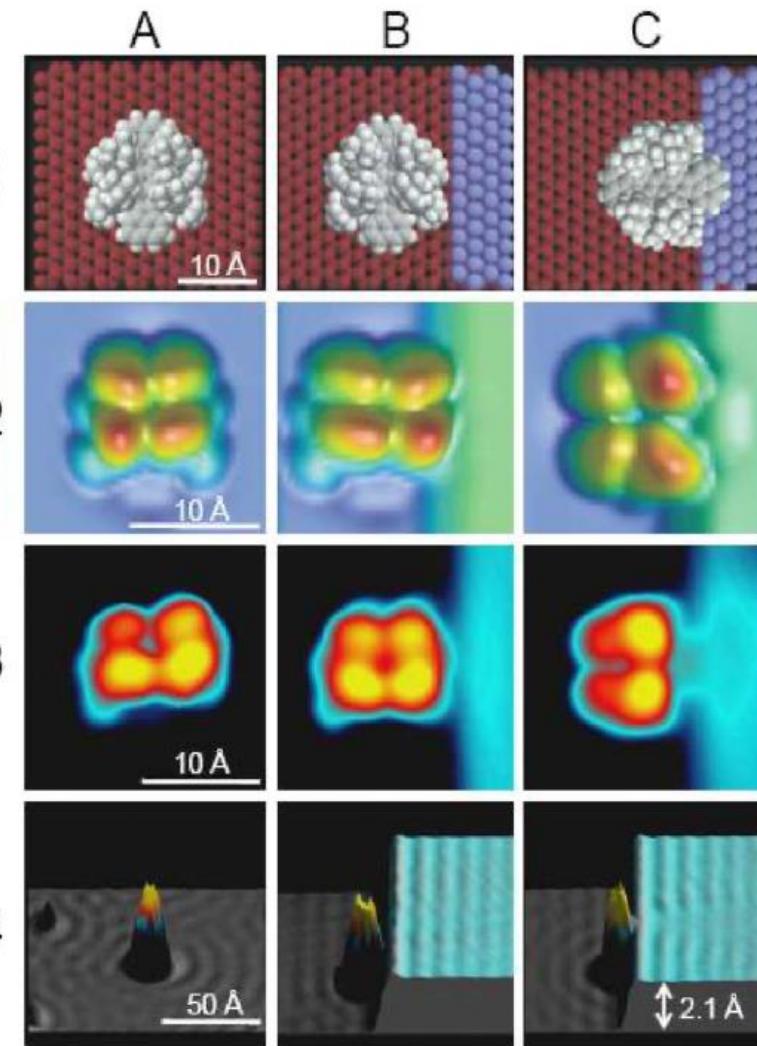
- The local density of states (LDOS) at EF surrounding the adatom is marked by a circular standing wave pattern caused by the interference of incident and scattered surface state electrons

$$\Delta \text{LDOS}(\rho) \propto \frac{1}{k\rho} \left( \cos^2(k\rho - \frac{\pi}{4} + \delta_0) - \cos^2(k\rho - \frac{\pi}{4}) \right)$$

distance                          Phase shift

## 6.11 Rastertunnelspektroskopie

### Kontaktierung des 2D Elektronengases durch ein Lander-Molek l



Wenn Landermolek l eine Stufe einer Cu(111) Oberfl che mit dem organischen Ringsystem ber hrt (C), kommt es zu Streuung.

Das Molek l kontaktiert das 2D Elektronengas.

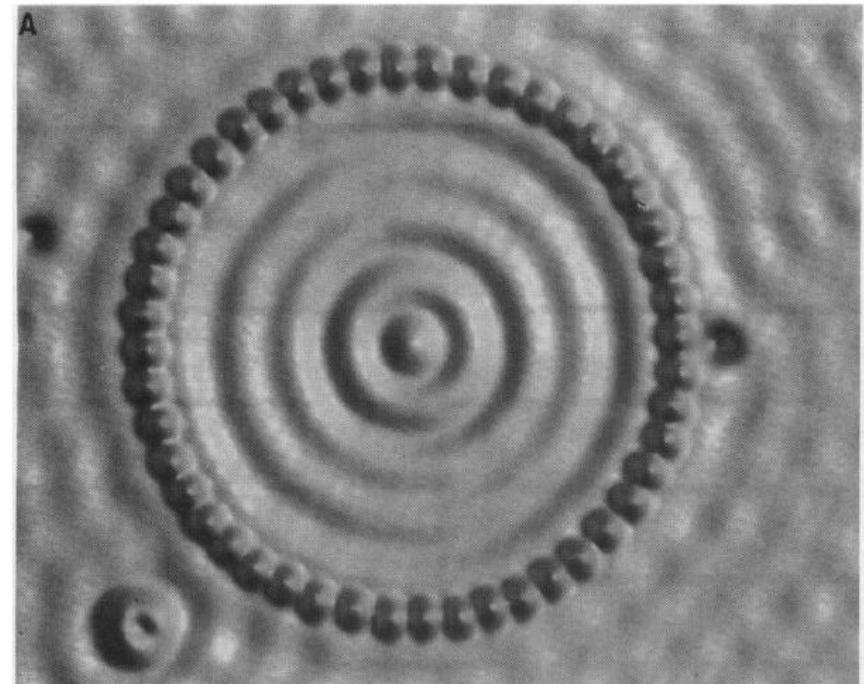
FU Berlin

## 6.11 Rastertunnelspektroskopie

### Quantum Corral

- A circular corral of radius 71.3 Å was constructed in this way out of 48 iron adatoms.

→ Manipulation von Streuern auf der Oberfläche mit 2DEG ermöglicht Experimente zur fundamentalen Quantenmechanik

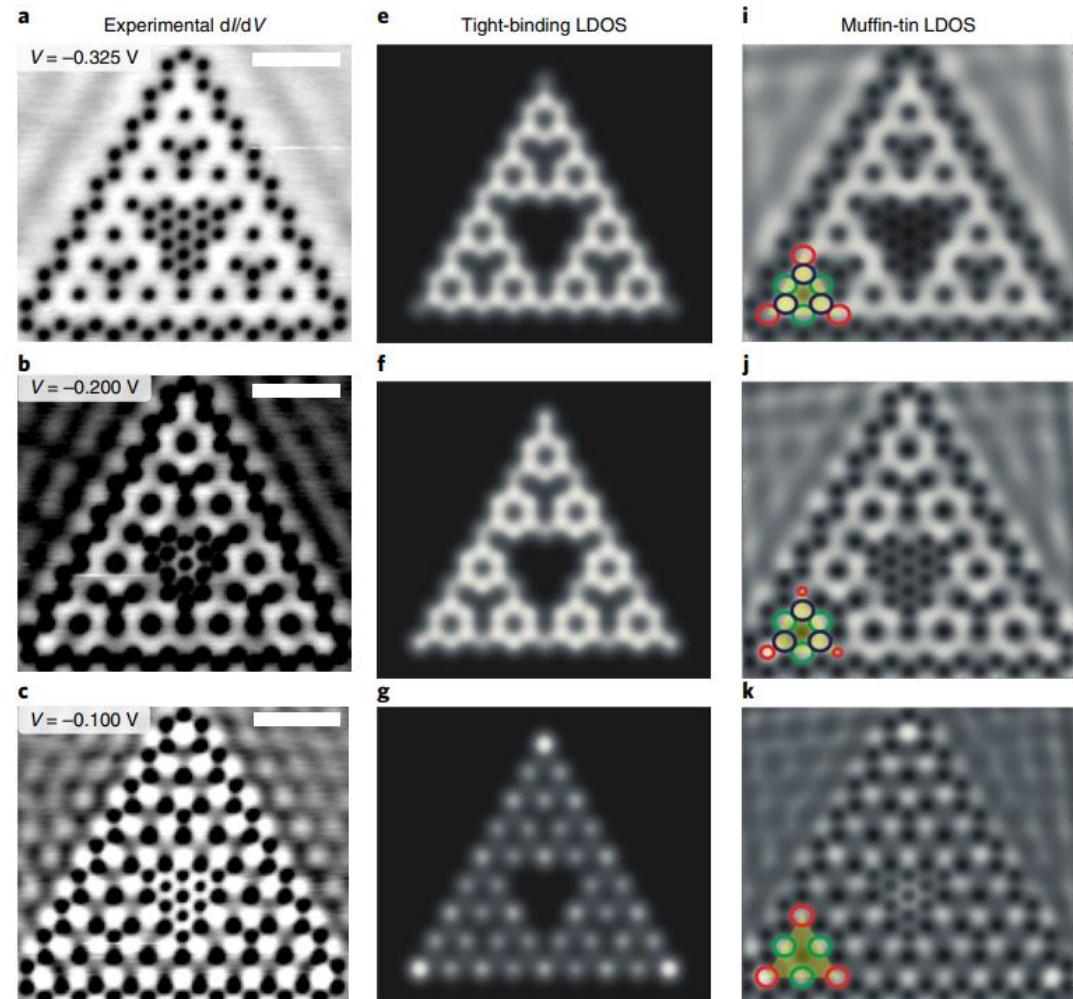


**Fig. 2.** Spatial image of the eigenstates of a quantum corral. **(A)** 48-atom Fe ring constructed on the Cu(111) surface ( $V = 0.01$  volt,  $I = 1.0$  nA). Average diameter of ring (atom center to atom center) is 142.6 Å. The ring encloses a

## 6.11 Rastertunnelspektroskopie

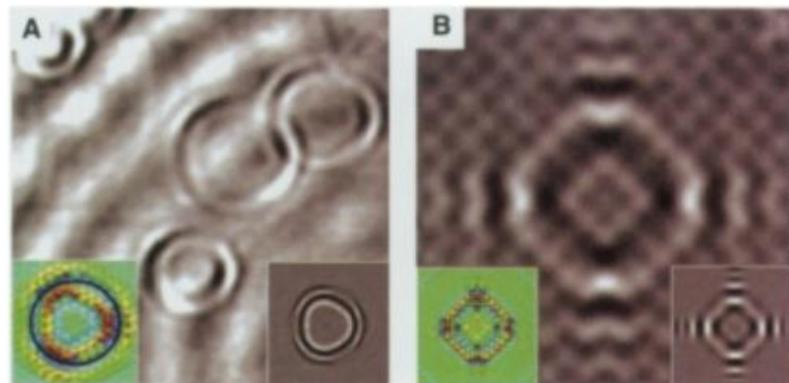
### CO molecules on a Cu (111)

- Electronic quantum fractals can be artificially created by atomic manipulation in a scanning tunnelling microscope.
- Sierpiński triangle with Hausdorff dimension  $\log(3)/\log(2)=1.58$



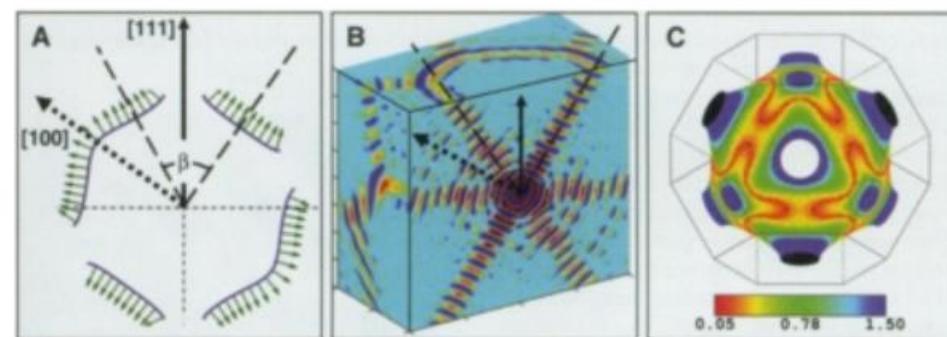
## Seeing the Fermi Surface in Real Space by Nanoscale Electron Focusing

Alexander Weismann,<sup>1,2</sup> Martin Wenderoth,<sup>1\*</sup> Samir Lounis,<sup>3</sup> Peter Zahn,<sup>4</sup> Norbert Quaas,<sup>1</sup> Rainer G. Ulbrich,<sup>1</sup> Peter H. Dederichs,<sup>3</sup> Stefan Blügel<sup>3</sup>



**Fig. 1.** STM topographies of (A) four Co-Atoms below the Cu(111) surface (9 by 9 nm, -80 mV, 1 nA) and (B) one Co Atom below the Cu(100) surface (3.5 by 3.5 nm, 10 mV, 2 nA). The right insets show (4 by 4 nm) calculated LDOS using Eq. 2, whereas the left insets refer to DFT calculations.

- Auch im Volumen lassen sich Streuer identifizieren

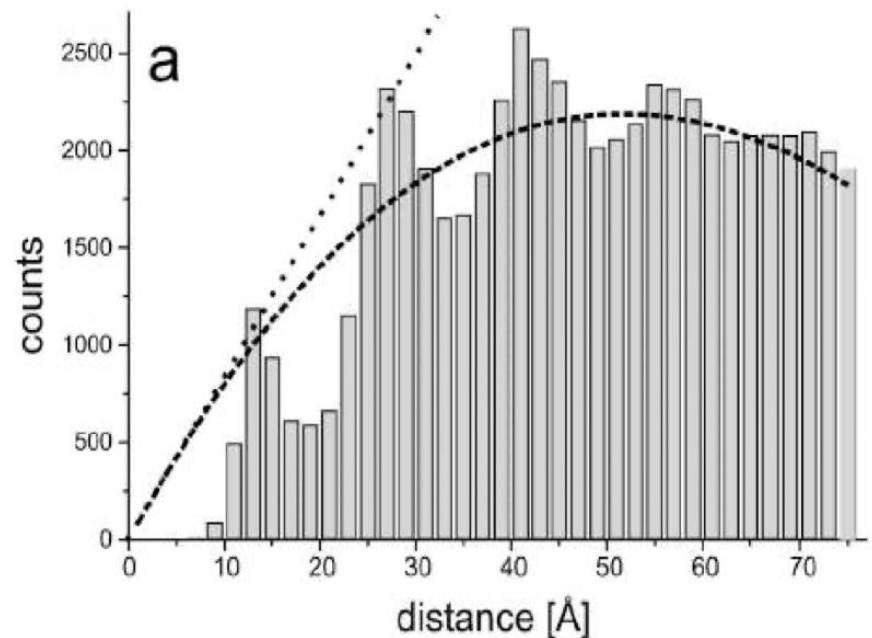
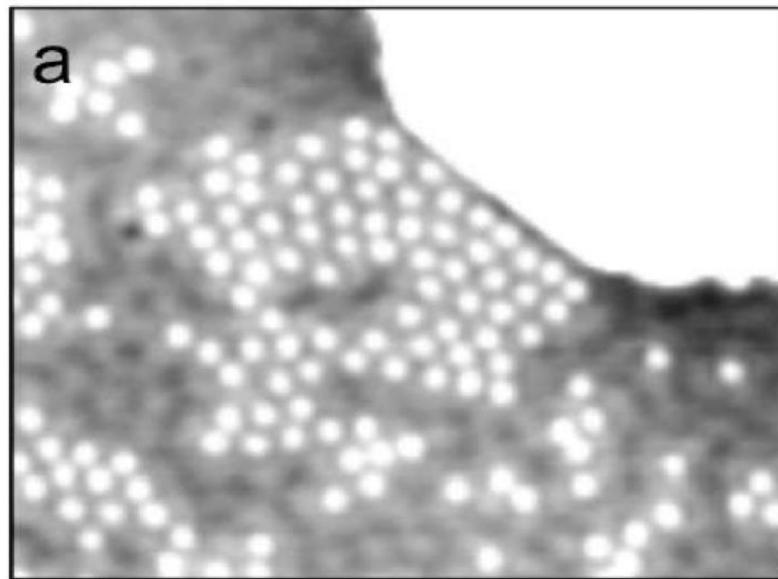


**Fig. 3.** (A) Cross section of the Cu Fermi surface showing areas of reduced curvature and band-gaps in [111] directions. (B) Corresponding propagator  $[-i\text{m}G_0(x, x', \epsilon_f)]$  with strong electron focusing onto hollow-conelike beams around [111]. (C) The Gaussian curvature of the Cu Fermi surface is represented with color. The drawing plane is oriented perpendicular to the [111] direction. Small curvatures represented in red lead to high amplitudes of the LDOS oscillations.

## 6.11 Rastertunnelspektroskopie

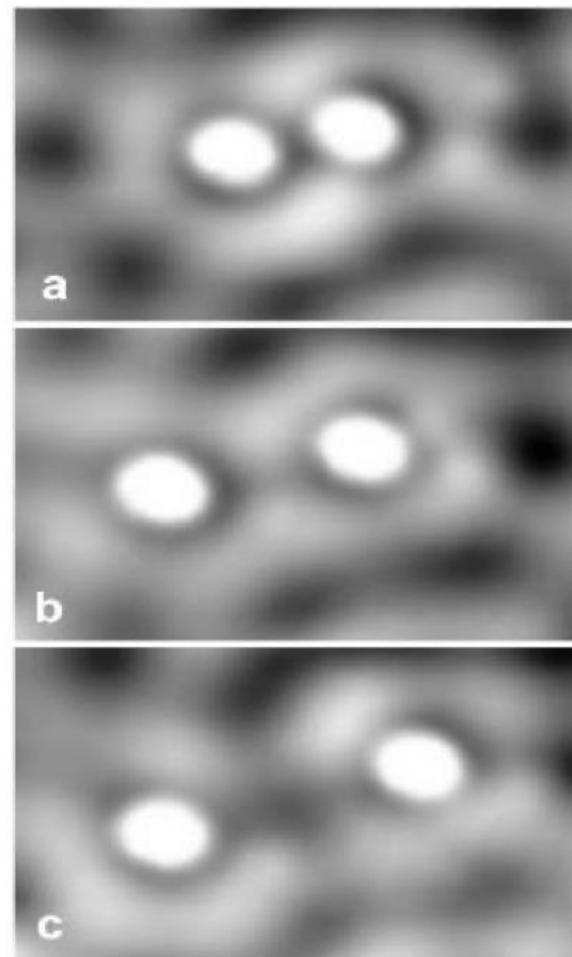
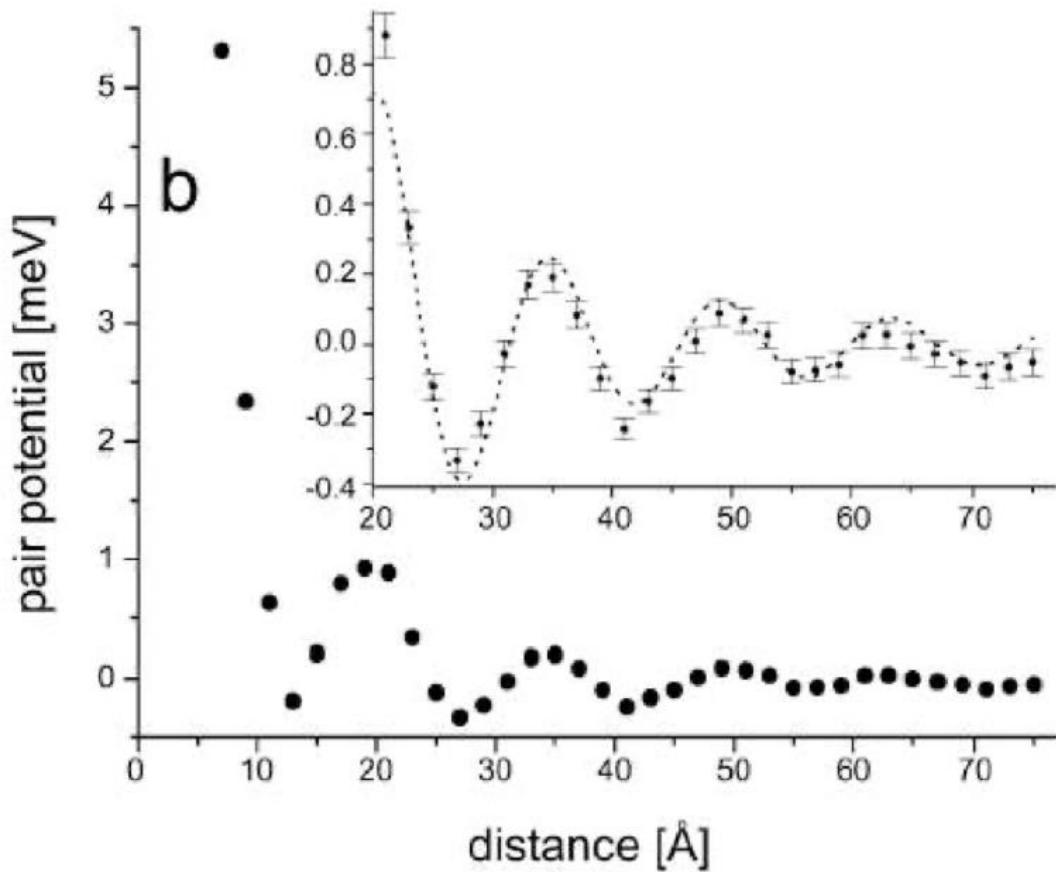
- Oberflächenzustände können Adsorption beeinflussen  
→ Substratvermittelte langreichweitige oszillierende Wechselwirkung zwischen Adatomen

Cu auf Cu(111)



## 6.11 Rastertunnelspektroskopie

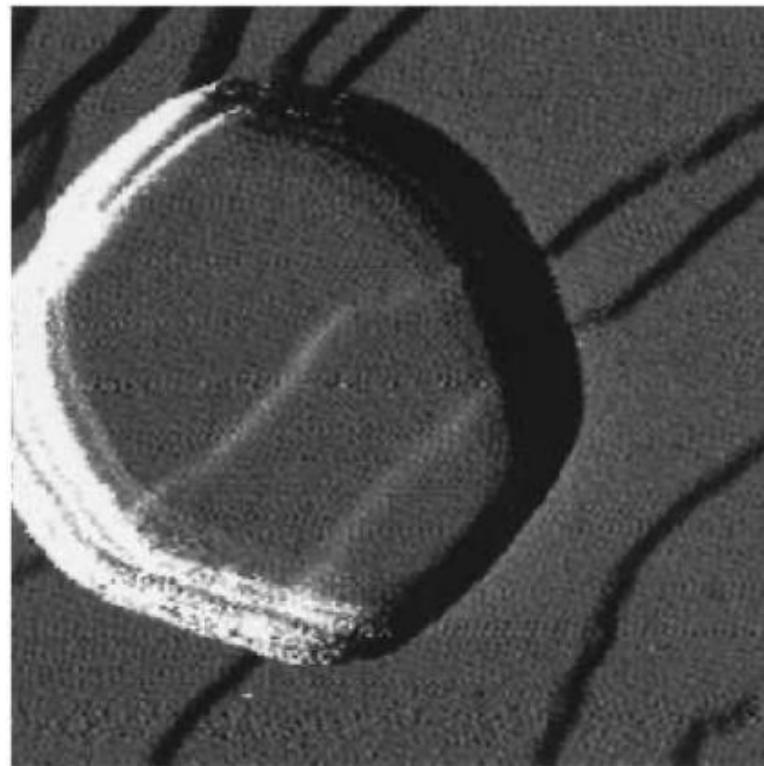
### Stehende Wellen des Oberflächenzustandes



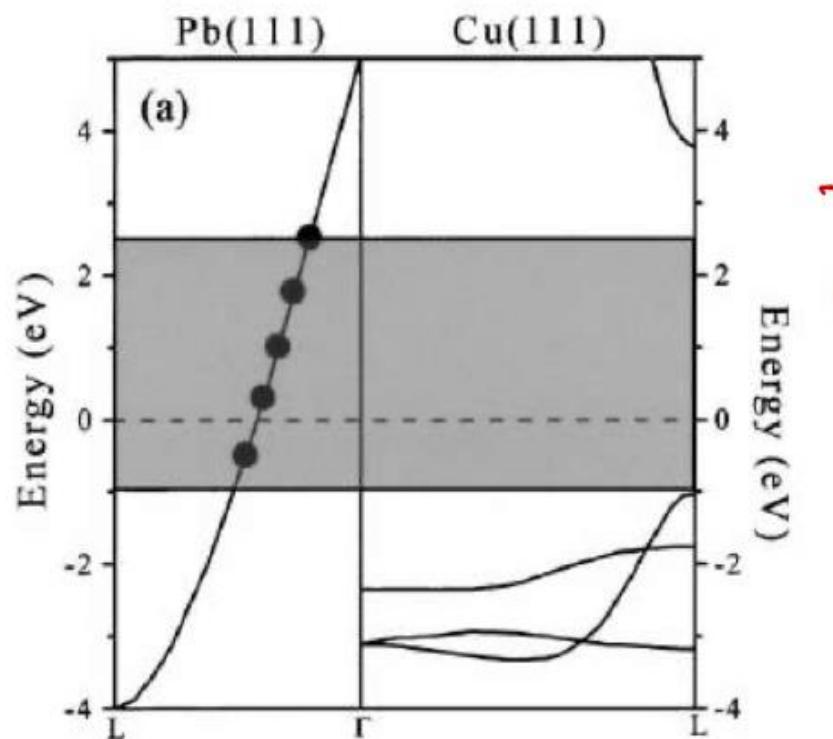
## 6.11 Rastertunnelspektroskopie

Pb Schichten auf Cu(111)

Pb Inseln auf Cu(111)



Bandstruktur senkrecht zur Oberfläche

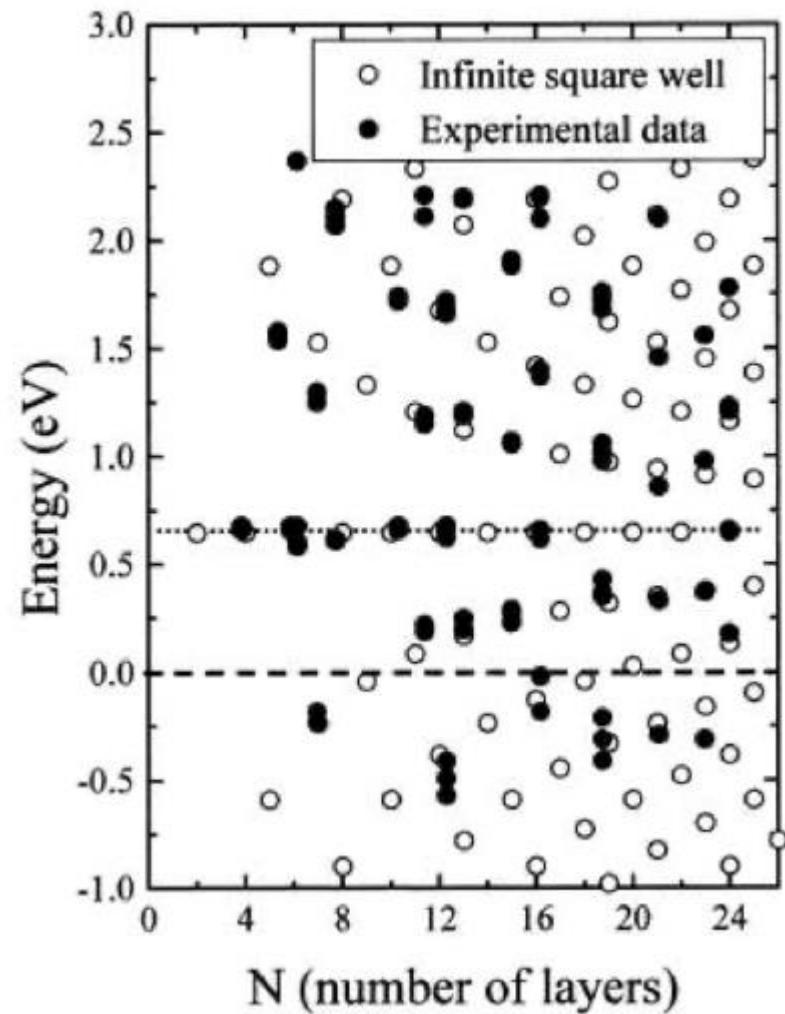
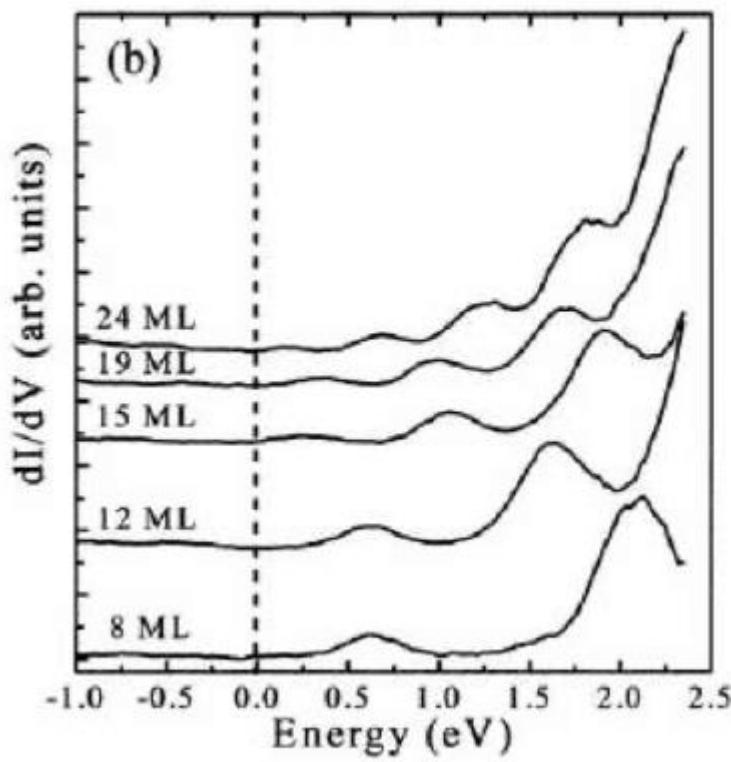


Elektronen in Pb Schicht sind in einem Quantentrog senkrecht zur Oberfläche eingeschlossen.

## 6.11 Rastertunnelspektroskopie

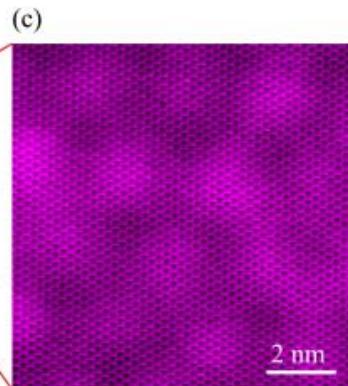
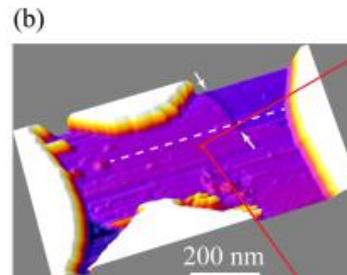
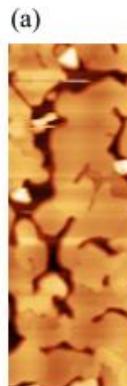
### Die elektronische Struktur Pb auf Cu(111)

#### Tunnelspektren

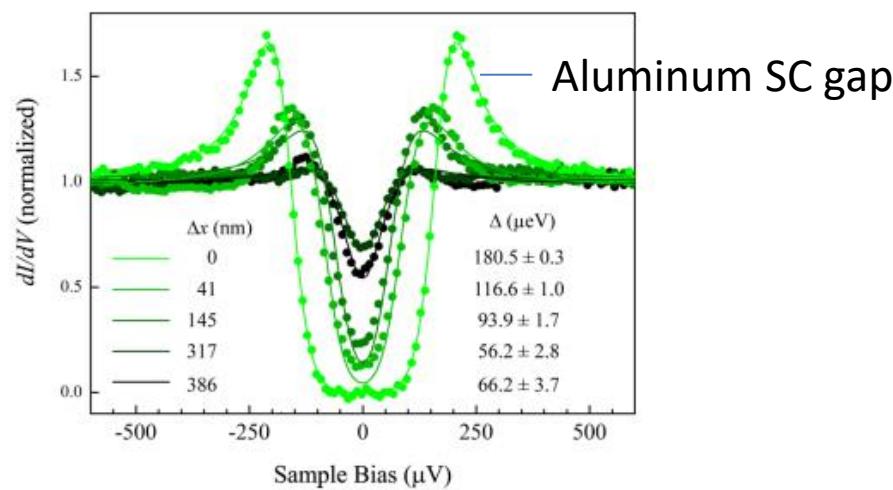


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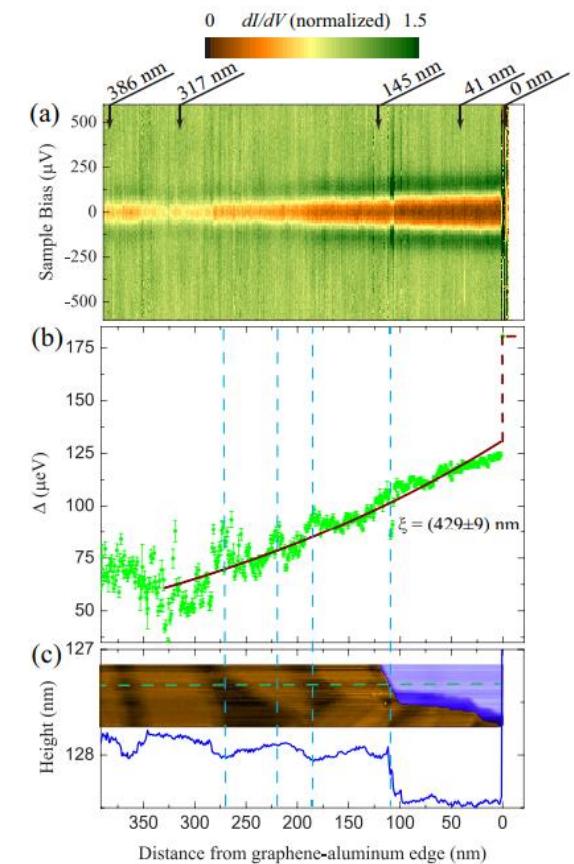
- More Examples: Superconducting gap and Proximity effect:



Aluminum on graphene

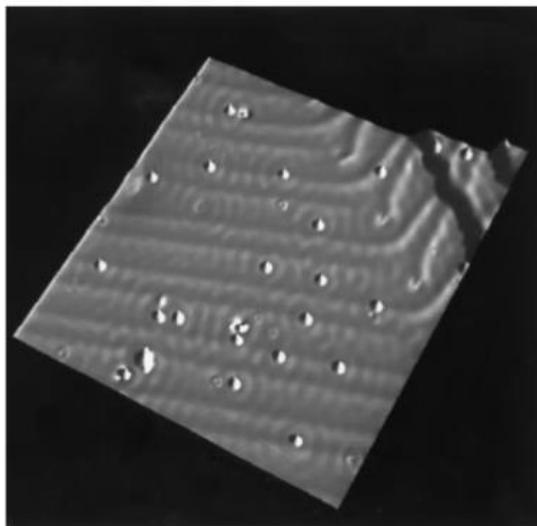


Ortsabhängige STS  
→ Proximity effect

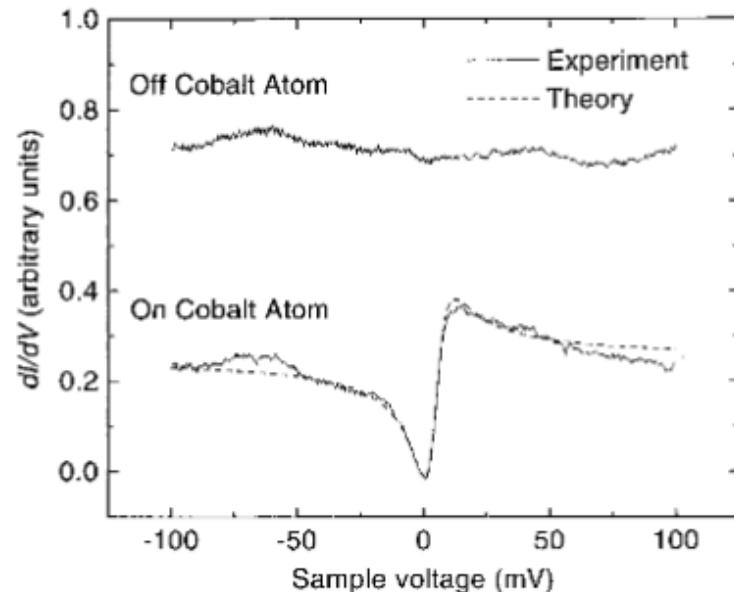


## 6.11 Rastertunnelspektroskopie

- Examples: Single magnetic impurities on surfaces



**Fig. 1.** Constant-current image ( $400 \text{ \AA}$  by  $400 \text{ \AA}$ ) of the Au(111) surface after deposition of 0.001 monolayer of Co at 4 K (tunnel parameters:  $I = 0.5 \text{ nA}$ ,  $V = 0.1 \text{ V}$ ). Approximately 22 Co atoms can be seen nestled among the ridges of the Au(111) herringbone reconstruction.



**Kondo-Effect:**

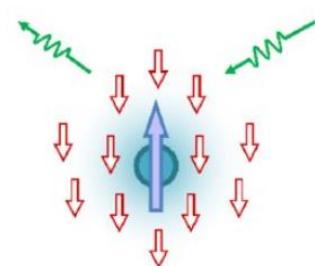
- magnetic impurity in a conducting host at low temperatures
- first discovered in transport experiments

## 6.11 Rastertunnelspektroskopie

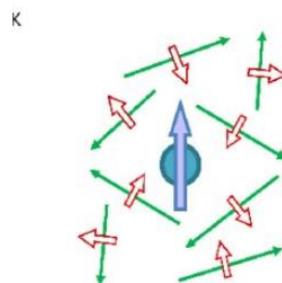
- Impurity spectral function  $A(\omega)$  of a single-level Anderson impurity model

$$H = \sum_{k,\sigma} \epsilon_k c_{k\sigma}^\dagger c_{k\sigma} + \sum_{\sigma} \epsilon_d d_{\sigma}^\dagger d_{\sigma} + U d_{\uparrow}^\dagger d_{\uparrow} d_{\downarrow}^\dagger d_{\downarrow} + \sum_{k,\sigma} V_k (d_{\sigma}^\dagger c_{k\sigma} + c_{k\sigma}^\dagger d_{\sigma}),$$

**cond. e**      **impurity**      **on-site Coulomb repulsion**      **hybridization**



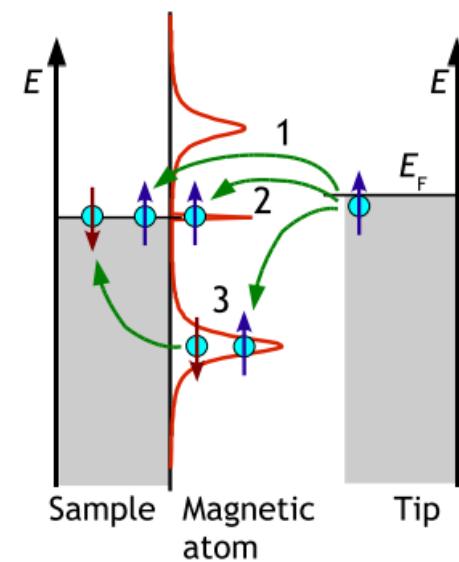
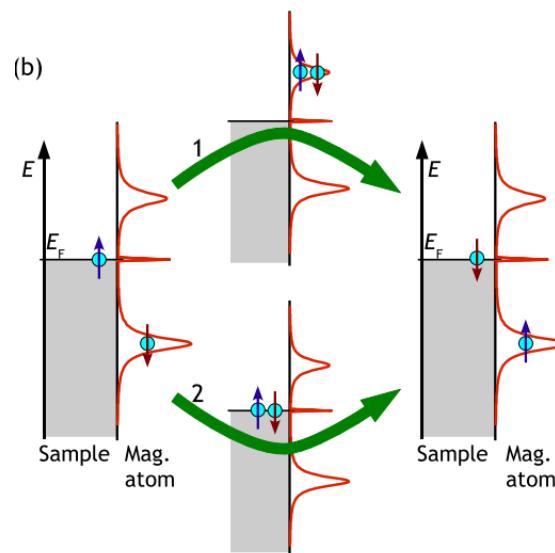
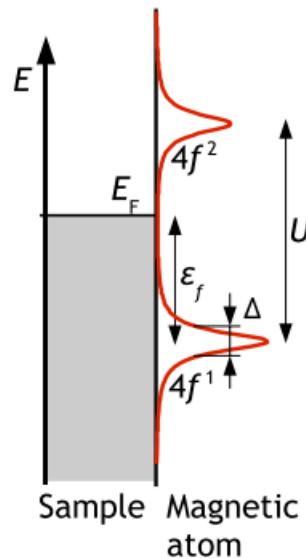
- Below  $T_K$ : Kondo state is formed with the local spin moment at the impurity, screened by the spins of conduction electrons in the leads.



- Above  $T_K$ : enhanced thermal motion of conduction electrons destroys the Kondo state.

## 6.11 Rastertunnelspektroskopie

### Intermediate step



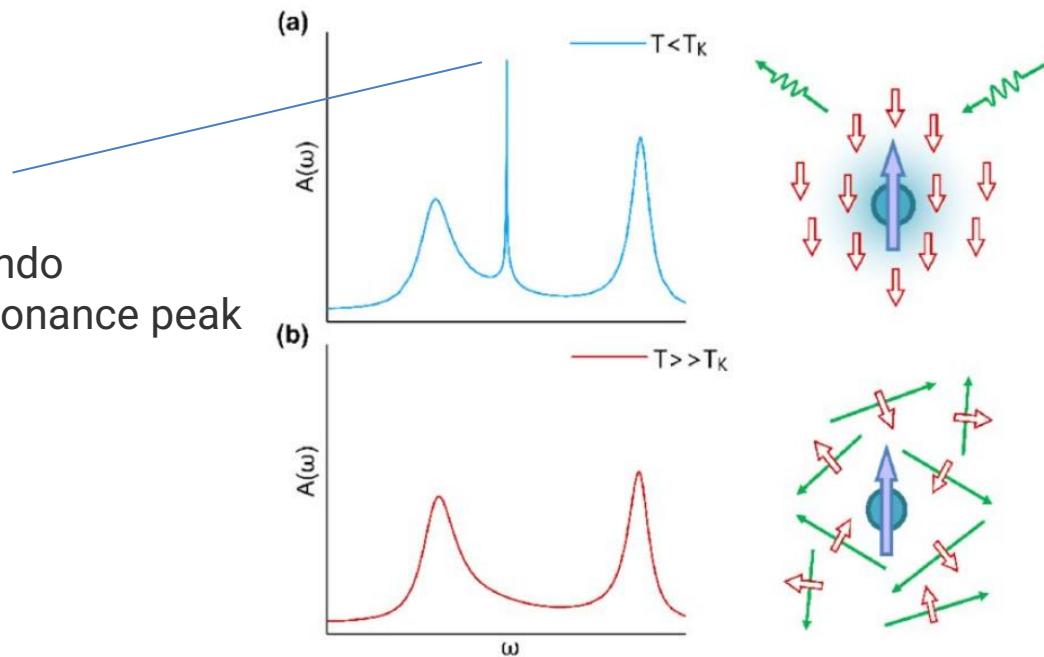
- energy-dependent DOS of a single magnetic adatom on a metal surface
- spin of the singly occupied 4f state can be flipped by a bulk electron of opposite spin via 2 processes
- Different tunnel paths of a probing tip

**Kondo resonance width:**

$$\Gamma = k_B T_K \simeq \sqrt{2\Delta \frac{U}{\pi}} \exp \left[ -\frac{\pi}{2\Delta} \left( \left| \frac{1}{\epsilon_f} \right| + \left| \frac{1}{\epsilon_f + U} \right| \right)^{-1} \right]$$

## 6.11 Rastertunnelspektroskopie

Kondo  
resonance peak



- Below  $T_K$ : Kondo state is formed with the local spin moment at the impurity, screened by the spins of conduction electrons in the leads.
- Above  $T_K$ : enhanced thermal motion of conduction electrons destroys the Kondo state.

# 6.11 Rastertunnelspektroskopie

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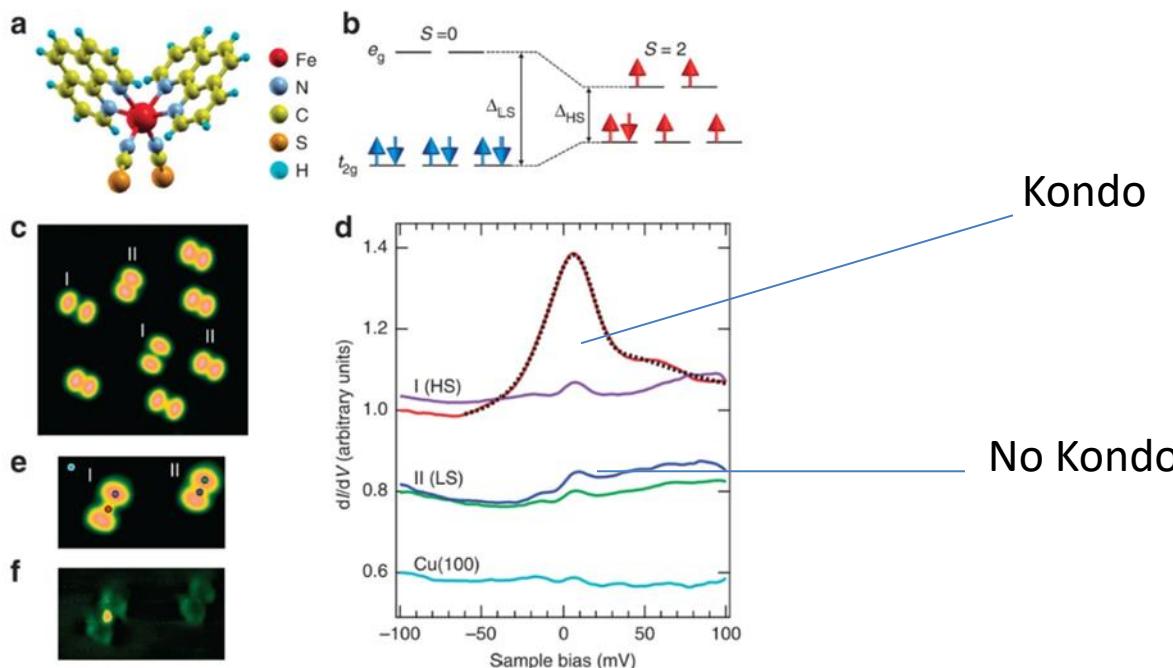
## Robust spin crossover and memristance across a single molecule

Toshio Miyamachi , Manuel Gruber, Vincent Davesne, Martin Bowen, Samy Boukari, Loïc Joly, Fabrice Scheurer, Guillaume Rogez, Toyo Kazu Yamada, Philippe Ohresser, Eric Beaurepaire & Wulf Wulfhekel

*Nature Communications* 3, Article number: 938 (2012) | Cite this article

2433 Accesses | 323 Citations | 42 Altmetric | Metrics

Figure 1: SCO Fe-phen molecules on bare Cu(100).



## 6.11 Rastertunnelspektroskopie

### Literatur

- Oberflächenzustände: Ibach, S. 394-407
- Rastertunnelspektroskopie: Fauster S. 26-36  
Fauster, S. 135-137